A high-efficiency continuous class-F power amplifier design using simplified real frequency technique

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ABSTRACT
The fourth-generation (4G) wireless communication has been deployed in many countries. However, there are still some problems such as spectrum crisis due to the increase of wireless mobile devices and servicing. Therefore, the fifth-generation (5G) communication system will be employed at some different spectrum other than 4G frequency band. The radio frequency power amplifier (RFPA) is the key component of the 5G system. In this paper, a broadband continuous class-F (CCF) RFPA is designed for the 5G frequency band from 3.3-4.3 GHz. The input and output matching network are designed using the simplified real frequency technique (SRFT). Using a 10W GaN CGH40010F Cree device, the efficiency of the RFPA achieved greater than 70.7% for the whole frequency band with a maximum of 81.5%. The output power and the gain are more than 40 dBm and 10 dB respectively.

Keywords:
Broadband
Continuous class-F
Fifth-generation communication
High efficiency
Simplified real frequency

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1. INTRODUCTION
With the evolution of wireless technology, the use of wireless devices increasing day by day in different fields. Likewise, the requirement of the communication speed and bandwidth of the system are also increased. To meet the demand of the users, the next fifth-generation (5G) communication system will be implemented very soon. The upcoming 5G network has a large bandwidth and high data rates facilities which can be deployed for multimedia application. The 5G system will operate mainly in two frequency bands: low-frequency band up to 6 GHz and high-frequency band from 24 to 86 GHz [1]. In the low-frequency band, the communication network of different countries will operate at different operating frequencies. The nominated frequency bands of some countries are shown in Table 1 [2, 3]. From Table 1, it is seen that the lowest frequency is 3.3 GHz and the highest frequency is 4.2 GHz.

The crucial component of a wireless communication system is the radio frequency power amplifier (RFPA) [4]. The RFPA is used in the transceiver and usually consume largest power compare to the other components [5]. RFPAs are divided basically into two types: the biasing class and the switching class [6]. In the biasing class, the RFPA is classified such as Class A, B, AB and C depending on their current conduction angle. The switching class RFPA turn on and off are controlled by the input signal. Some examples of switching class RFPA are Class D, E, F J, H and S. Two widely used switching RFPA are class-E and class-F. These two RFPA are used because it can achieve high efficiency. Nevertheless, at the high frequency, the efficiency of the class-E amplifier decreases because of the limitation of charging capacity [7]. Whereas in case of a class-F amplifier, there is no charging limitation problem. In addition, the theoretical efficiency 100% can be achieved by properly terminating infinite
number of harmonics at the output. The class-F RFPA is a good choice for narrowband applications but not suitable for large band applications [8]. To alleviate the narrow band problem, waveform engineering-based continuous class-F (CCF) RFPA technique has been applied. However, there is a problem of anticlockwise rotation of fundamental and harmonics impedance at the current generator plane [9] when using this technique. The anticlockwise impedance rotation is not possible to realize using a matching network. By carefully selecting the optimum impedance at the generator plane this problem can be solved.

Table 1. 5G spectrum allocation of different countries in the low-frequency band

<table>
<thead>
<tr>
<th>Country</th>
<th>USA</th>
<th>Finland</th>
<th>France</th>
<th>Germany</th>
<th>Ireland</th>
<th>Italy</th>
<th>Russia</th>
<th>Spain</th>
<th>United Kingdom</th>
<th>China</th>
<th>Japan</th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency (GHz)</td>
<td>3.55-3.7</td>
<td>3.7-4.2</td>
<td>3.4-3.8</td>
<td>3.4-3.8</td>
<td>3.6-3.8</td>
<td>3.4-3.8</td>
<td>3.4-3.8</td>
<td>3.4-3.8</td>
<td>3.4-3.6, 3.6-3.8</td>
<td>3.3-3.6</td>
<td>3.6-4.2</td>
</tr>
</tbody>
</table>

In this paper, a broadband CCF RFPA is designed for the frequency range of 3.3 to 4.3 GHz. The simplified real frequency technique (SRFT) has been used for the designing of input and output matching networks. In section II, the theory of CCF RFPA is discussed. The methodology of the designing of the CCF amplifier is proposed in section III. Section IV represents the simulated result of the designed PA. Finally, conclusions are presented in section V.

2. THEORY OF CCF MODE

The conventional class-F mode RFPA is derived from the class-B amplifier by properly terminating the harmonics impedance. The output matching network is designed in such a way that it provides short circuit termination at even harmonics and open circuit termination at odd harmonics. Thus, conventional class-F RFPA provide half rectified sine wave and square shape voltage wave. The ideal class-F power amplifier provide the non-overlap between voltage and current [10]. Therefore, the theoretical efficiency of conventional class-F RFPA is 100%. The conventional class-F amplifier provides better performances for narrowband application but it is not suitable for the wideband application. The latest technique for achieving good performance for the wideband applications is continuous class-F (CCF) RFPA. For the case of CCF RFPA, the drain voltage waveform is multiplied by the term \((1 - \gamma \sin \theta)\). Then, the equation of the drain voltage and current waveform can be written as follows [11]

\[
\begin{align*}
    v_d &= \left(1 - \frac{2}{\sqrt{3}} \cos \theta\right)^2 \left(1 + \frac{1}{\sqrt{3}} \cos \theta\right) (1 - \gamma \sin \theta) \\
    i_d &= \frac{1}{\pi} + \frac{1}{2} \cos \theta + \frac{2}{3\pi} \cos 2\theta - \frac{2}{15\pi} \cos 4\theta + \frac{2}{35\pi} \cos 6\theta + \cdots
\end{align*}
\]

(1)
(2)

The value of \(\gamma=0\) corresponds to the conventional class-F power amplifier. By changing the value of the \(\gamma\) from -1 to 1 a family of voltage curves obtained that provide the new design space for RFPA design [12]. The performances of the new type of RFPA are the same for every value of \(\gamma\) between this range. The fundamental and harmonics impedances of the CCF power amplifier are calculated from the ratio of drain voltage and drain current. The first three harmonics impedance of the CCF RFPA is as follows:

\[
\begin{align*}
    Z_{f} &= R_{opt}^2 + j R_{opt} \gamma \\
    Z_{2,f} &= -j R_{opt}^2 \frac{7\sqrt{3} \pi}{24} \gamma \\
    Z_{3,f} &= \infty
\end{align*}
\]

(3)

When \(\gamma\) is varied from -1 to +1 then the locus of fundamental impedances rotate in the clockwise direction and second harmonics impedances are rotating in anticlockwise direction but the third harmonic remain standstill at infinite impedance point as shown in Figure 1. Therefore, the broadband RFPA can be achieved by designing the matching network that follows the fundamental and harmonics impedance locus.
3. BROADBAND CCF AMPLIFIER SYNTHESIS AND DESIGN

The design of CCF RFPA is conducted by using the nonlinear model of the CGH40010 10W gallium nitride (GaN) HEMT device from the CREE company. Load pull and source pull are a widely used technique in the design of the RFPA. It allows us to find the optimum impedance at the desired frequency considering the performances such as efficiency, gain and output power. This amplifier is designed for the 5G frequency range from 3.3 to 4.3 GHz. The load-pull and source pull method are applied to find optimum impedance in the whole frequency band with a spacing 100 MHz. The optimum impedance values for fundamental, second harmonics and third harmonics are shown in Table 2. The single matching problem occurs when the generator impedance is resistive while the load impedance is complex. Since this RFPA is designed for the 50 Ω input and output reference impedance while the optimum source and load impedance are complex, so this case is a single matching problem. The distributed SRFT algorithm is applied to fit the fundamental load impedances well as the second and third harmonics impedance [13].

Table 2. The optimum impedances obtained from load-pull and source pull technique

<table>
<thead>
<tr>
<th>frequency</th>
<th>$Z_{L1}$</th>
<th>$Z_{L2}$</th>
<th>$Z_{L3}$</th>
<th>$Z_{S1}$</th>
<th>$Z_{S2}$</th>
<th>$Z_{S3}$</th>
<th>Gain</th>
<th>$P_{out}$</th>
<th>PAE</th>
</tr>
</thead>
<tbody>
<tr>
<td>3.3</td>
<td>14.4+j13.5</td>
<td>-2.7-j0.19</td>
<td>71+j839</td>
<td>1.9-j11.4</td>
<td>1.9-j11.4</td>
<td>1.9-j11.4</td>
<td>10.64</td>
<td>40.64</td>
<td>76.38</td>
</tr>
<tr>
<td>3.4</td>
<td>14+j12.2</td>
<td>0.4+j2</td>
<td>71+j839</td>
<td>1.8-j12.2</td>
<td>1.7-j12.3</td>
<td>1.8-j12.1</td>
<td>10.02</td>
<td>40.02</td>
<td>66.4</td>
</tr>
<tr>
<td>3.5</td>
<td>8.4+j7.4</td>
<td>0.15+j2</td>
<td>71+j839</td>
<td>1.6-j13.2</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.15</td>
<td>40.15</td>
<td>72.00</td>
</tr>
<tr>
<td>3.6</td>
<td>8.9+j5.4</td>
<td>0.15+j2</td>
<td>71+j839</td>
<td>1.6-j14.0</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.73</td>
<td>40.73</td>
<td>75.20</td>
</tr>
<tr>
<td>3.7</td>
<td>9.2+j3.4</td>
<td>0.15+j2</td>
<td>70.5+j839</td>
<td>1.3-j14.8</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>11.19</td>
<td>41.192</td>
<td>76.68</td>
</tr>
<tr>
<td>3.8</td>
<td>9.2+j3.4</td>
<td>0.15+j2</td>
<td>70.5+j839</td>
<td>1.1-j15.9</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.93</td>
<td>40.93</td>
<td>78.19</td>
</tr>
<tr>
<td>3.9</td>
<td>9.2-j3.4</td>
<td>0.15-j2</td>
<td>70.5+j839</td>
<td>1.3-j17.7</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.42</td>
<td>40.42</td>
<td>77.41</td>
</tr>
<tr>
<td>4</td>
<td>11.0+j2.8</td>
<td>0.15+j2</td>
<td>70.5+j839</td>
<td>1.2-j18.3</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.12</td>
<td>40.12</td>
<td>72.00</td>
</tr>
<tr>
<td>4.1</td>
<td>9.4+j2.6</td>
<td>0.15+j2</td>
<td>70.5+j839</td>
<td>1.2-j19.1</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.28</td>
<td>40.28</td>
<td>76.11</td>
</tr>
<tr>
<td>4.2</td>
<td>8.1+j1.15</td>
<td>0.15+j2</td>
<td>70.5+j839</td>
<td>1.2-j20.0</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>10.13</td>
<td>40.13</td>
<td>75.93</td>
</tr>
<tr>
<td>4.3</td>
<td>9.8-j1.7</td>
<td>0.15+j2</td>
<td>70.5+j839</td>
<td>1.6-j20.5</td>
<td>1.7-j12.3</td>
<td>1.9-j11.4</td>
<td>11.53</td>
<td>41.53</td>
<td>75.34</td>
</tr>
</tbody>
</table>

$Z_{L1}$: Load impedance at the fundamental frequency, $Z_{L2}$: Load impedance at 2nd harmonics, $Z_{L3}$: Load impedance at 3rd harmonics, $Z_{S1}$: Load impedance at the fundamental frequency, $Z_{S2}$: Source impedance at 2nd harmonics, $Z_{S3}$: Load impedance at 3rd harmonics, $P_{out}$: Output power in dBm, PAE: power aided efficiency.

3.1. Simplified real frequency technique (SRFT)

The SRFT algorithm was first developed by the Yarman and Carlin which was mainly focused on the lump elements LC network synthesis. The SRFT algorithm was then evolved and modified for the distributed network synthesis. In the SRFT algorithm, the input reflection coefficient of the matching network $S_{11}(p)$ can be represented as [14-17]
where \( h(p) \) and \( g(p) \) are the polynomials of order \( n \). The order of the polynomial determines the total number of reactive elements in the matching network. The other scattering parameter \( S \) of the matching network (which is also known as the equalizer), can be determined from the \( S_{11} \) by employing the Belevitch representation shown in (5) and (6).

\[
S_{12} = S_{21} = \pm \frac{f(p)}{g(\lambda)}
\]

\[
S_{22} = -(-1)^{k} \frac{h(-p)}{g(p)}
\]

Note that, \( k \) is an integer that specifies the order of the zeros of the transmission at the origin. To measure the matching quality between the 50 \( \Omega \) load and the active device, the transducer power gain (TPG) is calculated. The TPG can be expressed as follows:

\[
TPG(\omega) = \frac{|S_{21}|^2(1 - |\Gamma_{L}|^2)}{|1 - S_{11}\Gamma_{L}|^2}
\]

where, \( \Gamma_{L} \) is the normalized load reflection coefficient. For the lossless condition of the equalizer network, \( |S_{21}|^2 \) can be written as follows:

\[
|S_{21}|^2 = 1 - |S_{11}|^2 = \frac{|f(p)|^2}{g(p)g(-p)}
\]

Thus, by substituting these values in (7), the TPG becomes:

\[
TPG(\omega) = \frac{[f(p)f(-p)](1 - |\Gamma_{L}|^2)}{h(p),h(-p)[1 + |\Gamma_{L}|^2] + f(p)f(-p) - 2\text{real}(|\Gamma_{L}|h(p)g(-p))}
\]

Then, the TPG is maximized as flat as possible over the band of interest using the least square method. The optimized coefficients of \( h(p) \) corresponding to the optimized performance are calculated. The error function \( \delta \) can be written as:

\[
\delta = \sum_{i=1}^{m} T(\omega_{i}) - T_{0}
\]

where \( T(\omega_{i}) \) represents the transducer power gain at the frequency \( \omega_{i} \), \( T_{0} \) is the desired flat gain level and \( m \) is the number of the sampling frequency over the passband. The TPG is then calculated using (9). The error is minimized by updating the coefficient of the polynomial \( h(p) \). The increment of \( \Delta h \) is found by applying the Levenberg Marquard technique. When the final form of \( S_{11} \) is completed then the matching network is synthesized using the low pass ladder synthesis with the resistive termination.

### 3.2. Output matching network

The output matching network (OMN) is designed by employing the SRFT algorithm. The optimum impedance is obtained from the load-pull method. The optimum impedances are used for the designing of OMN. First of all, the frequency is normalized on the basis of the highest frequency of passband. Then, the output impedance is converted into the reflection coefficient by using 50 \( \Omega \) characteristic impedance. The initial value of all the coefficients of the polynomial \( h(p) \) was assumed -1. The order of the matching network was chosen to be 4. After that, the SRFT algorithm is applied to find a flat response over the whole band. When the desired flat response is achieved corresponding to the final value of the coefficient of the polynomial, \( h(p) \) is also found. TPG of the output matching network is shown in Figure 2(a). If the coefficient of the polynomial \( h(p) \) is known then the value of the polynomial \( g(p) \) can also be calculated easily. The scattering parameter \( S_{11} \) was used to find the normalized input impedance of the equalizer using the (11).
The low pass ladder LC synthesis technique is used to find the normalized value of the passive components. The normalized and denormalized passive component values are shown in the Table 3. The lump elements work very well at the low frequency but at the microwave frequency, the passive lump elements create two problems. Firstly, the lump elements are available in the limited range of values and the implementation of the lumped element at high frequency is very difficult. Secondly, the distance between the lump components is not negligible [18]. To solve this problem, Richard’s transformation is used to transform the lump components into the ideal transmission line whereas Kuroda’s identities are used to separate the elements by adding the transmission line. The performance of this transformation process is very accurate as the lump component. However, the implementation of this process is a little bit hard. So, a relatively easy way of transforming the lump elements to the microstrip line is called a stepped impedance technique [10]. The performances of this stepped impedance method are similar to the previous Richard’s transformation and Kuroda’s identities method but not very accurate due to the approximate equivalent circuit is used in this stepped impedance technique. In this stepped impedance technique, the series inductors are replaced by the high impedance transmission line section and the shunt capacitors are replaced by the low impedance transmission line section [18]. Finally, the ideal transmission line is converted into the microstrip line. The performances of the RFPA are optimized using the optimization technique in the keysight advanced design system (ADS) software that is used in the design process. The final OMN is shown in Figure 3.

![Table 3. Normalized and denormalized passive components value of OMN](image)

<table>
<thead>
<tr>
<th>Passive component</th>
<th>Normalized value</th>
<th>Denormalized value</th>
</tr>
</thead>
<tbody>
<tr>
<td>C1</td>
<td>0.8190</td>
<td>0.606 pF</td>
</tr>
<tr>
<td>L2</td>
<td>0.5653</td>
<td>1.05 nH</td>
</tr>
<tr>
<td>C3</td>
<td>2.2673</td>
<td>1.68 pF</td>
</tr>
<tr>
<td>L4</td>
<td>0.9165</td>
<td>1.70 nH</td>
</tr>
</tbody>
</table>

3.3. Input matching network

The input matching network (IMN) is consists of a stability network and matching network. The stability network is very important for a high power amplifier because high power oscillations can damage the active device [18]. The stability of the RFPA can be checked by using Rollett’s stability factor K greater than 1 and the magnitude of delta must be less 1 [19, 20]. The stability of the power amplifier is determined from the S-parameters [21]. Two popular techniques for stabilizing the circuit are parallel RC and series RC stabilization circuit [22]. In Figure 3, resistor 34.3Ω and capacitor 6pF are used parallelly to stabilized RFPA. The IMN is also designed using the same algorithm SRFT. In this case, the input of the h(p) polynomial is initialized for the fourth-order lowpass LC matching network but the TPG performance is not good over the band. Therefore, the order of the lowpass matching network was increased to six. The same procedure is repeated for the order of six and achieved good performance over the entire bandwidth. The TPG versus the normalized frequency is shown in Figure 2(b). After that, the input reflection coefficient $S_{11}(p)$ is determined from the polynomial h(p). Then, the input impedance is calculated from the reflection coefficient by using (11). The normalized matching network is extracted from the input impedance using the lowpass ladder synthesis. The normalized and the denormalized values of the lump components are shown in Table 4. The final input matching network is shown in Figure 3.
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Figure 2. Transducer power gain vs normalized frequency for, (a) output matching network, (b) input matching network

Figure 3. Complete circuit diagram of proposed RFPA

Table 4. Normalized and denormalized passive components value of IMN

<table>
<thead>
<tr>
<th>Passive component</th>
<th>Normalized value</th>
<th>Denormalized value</th>
</tr>
</thead>
<tbody>
<tr>
<td>L1</td>
<td>0.5702</td>
<td>1.06 nH</td>
</tr>
<tr>
<td>C2</td>
<td>6.2069</td>
<td>4.59 pF</td>
</tr>
<tr>
<td>L3</td>
<td>0.9953</td>
<td>1.84 nH</td>
</tr>
<tr>
<td>C4</td>
<td>1.4088</td>
<td>1.04 pF</td>
</tr>
<tr>
<td>L5</td>
<td>1.4583</td>
<td>2.70 nH</td>
</tr>
<tr>
<td>C6</td>
<td>0.9816</td>
<td>0.727 pF</td>
</tr>
</tbody>
</table>

4. PERFORMANCES OF THE PROPOSED RFPA

In the design of this RFPA, Rogers RO3006C substrate board with dielectric constant $\varepsilon_r = 6.5$ and thickness of 1.28mm are used. The gate of the GaN device is biased at -3.1V which corresponding to the drain current of 33mA and the drain voltage is 28V, as suggested by the datasheet. The RFPA is tested with continuous wave (CW) excitation at the frequency range of 3.3 to 4.3 GHz. The proposed RFPA is simulated using Keysight ADS. The voltage and current waveform at the intrinsic plane for 3.3 GHz and 4.3 GHz are obtained using the de-embedding network shown in Figure 4. The de-embedding network is extracted from S-parameter provided by Cree company [23]. The performances of the proposed RFPA for the whole frequency band are shown in Figure 5(a). It is seen that the efficiency is greater than 70.7 % all over the frequency band with a maximum of 81.5 %. The maximum power-added efficiency (PAE) is 75.0 % at 3.5 GHz. The PAE is greater than 63.7 % between the 3.3 GHz to 4.3 GHz. The output power is in the range from 40.0 to 41.0 dBm. The gain is 10-11 dB over the entire band at 30 dBm input power. The performances of RFPA at different input power levels are also shown in Figure 5(b). The PAE and the drain efficiency increases with the increase of input power. The gain and the output power decrease with the increase of the input power. However, at the higher input power, the amplifier becomes saturated and the efficiency does not increase linearly. The comparison between the proposed RFPA and the state-of-the-art broadband power amplifiers are listed in Table 5. It can be seen from Table 5 that the proposed RFPA presents the highest efficiency.
To implement the 5G network, a high efficiency RFPA is required. In this paper, the CCF mode RFPA has been designed for the new frequency range between 3.3 GHz to 4.3 GHz. The target impedance for fundamental and harmonics frequency was realized by using the SRFT algorithm. The designed amplifier achieved a very good performance. It shows that the maximum drain efficiency is 81.5% at 3.5 GHz. The gain of the RFPA is also greater than 10 dB over the entire frequency band. The output power is larger than 40 dBm which is very good because the 10W device is used. The proposed RFPA will be implemented in hardware. It is expected that hardware performance will be the same as simulation.

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**BIOGRAPHIES OF AUTHORS**

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*A high-efficiency continuous class-f power amplifier design using... (Md. Golam Sadeque)*
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**Associate Professor Dr. Mardeni Roslee** is an academician under Faculty of Engineering, Multimedia University, Cyberjaya, Malaysia. At Multimedia University, he is a current Deputy Director of Research Institute of Digital Connectivity, Chair of Centre of Wireless Technology and Chief Executive Officer (CEO) and Founder of Armada company. He serves as current Chair of IEEE Malaysia Comsoc/VTS, which is for recognized and selected members in professional organization, networking and interaction with like-minded multidisciplinary professionals. His current research interests are 5G/6G telecommunication, D2D, satellite, Internet of Things and radar communication. He has published over 90 indexed international journals and conference papers. He has 34 completed PhD and Masters and 10 ongoing postgraduate students. His contributions to academic and the engineering professional over the years have earned him recognitions nationally and internationally, he has awarded various international/local awards including being awarded the University Excellent Researcher Award for 2016 and 2018, respectively.